

60 V, 1 A PNP low VCEsat transistor

9 November 2023

### 1. General description

 $\mathsf{PNP}$  low  $\mathsf{V}_{\mathsf{CEsat}}$  transistor in a very small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package.

NPN complement: PBSS4160U

### 2. Features and benefits

- Low collector-emitter saturation voltage V<sub>CEsat</sub>
- + High collector current capability  ${\rm I}_{\rm C}$  and  ${\rm I}_{\rm CM}$
- + High collector current gain ( $h_{FE}$ ) at high  $I_C$
- High efficiency due to less heat generation
- Smaller required Printed-Circuit Board (PCB) area than for conventional transistors

### 3. Applications

- High voltage DC-to-DC conversion
- High voltage MOSFET gate driving
- High voltage motor control
- High voltage power switches (e.g. motors, fans)

### 4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	-60	V
I <sub>C</sub>	collector current		[1]	-	-	-1	А
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-	-2	А
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_{C}$ = -1 A; $I_{B}$ = -100 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C		-	255	340	mΩ

[1] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.

# nexperia

### 5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	
2	E	emitter		ç
3	С	collector		в
				E sym132
			SC-70 (SOT323)	

### 6. Ordering information

#### Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PBSS5160U	SC-70	plastic, surface-mounted package; 3 leads; 1.3 mm pitch; 2 mm x 1.25 mm x 0.95 mm body	<u>SOT323</u>		

### 7. Marking

#### Table 4. Marking codes

Type number	Marking code[1]
PBSS5160U	53%

[1] % = placeholder for manufacturing site code

### 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-80	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-60	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-5	V
I <sub>C</sub>	collector current		[1]	-	-0.7	А
			[2]	-	-0.86	А
			[3]	-	-1	А
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-2	А
IB	base current			-	-300	mA
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-1	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	250	mW
			[2]	-	350	mW
			[3]	-	415	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C

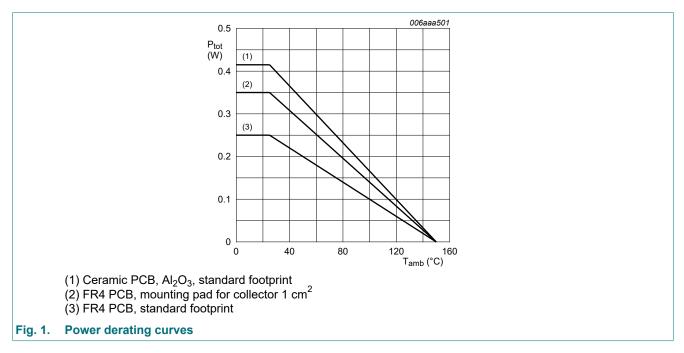
#### 60 V, 1 A PNP low VCEsat transistor

Symbol	Parameter	Conditions	Min	Max	Unit
T <sub>stg</sub>	storage temperature		-65	150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

[3] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.



### 9. Thermal characteristics

#### **Table 6. Thermal characteristics**

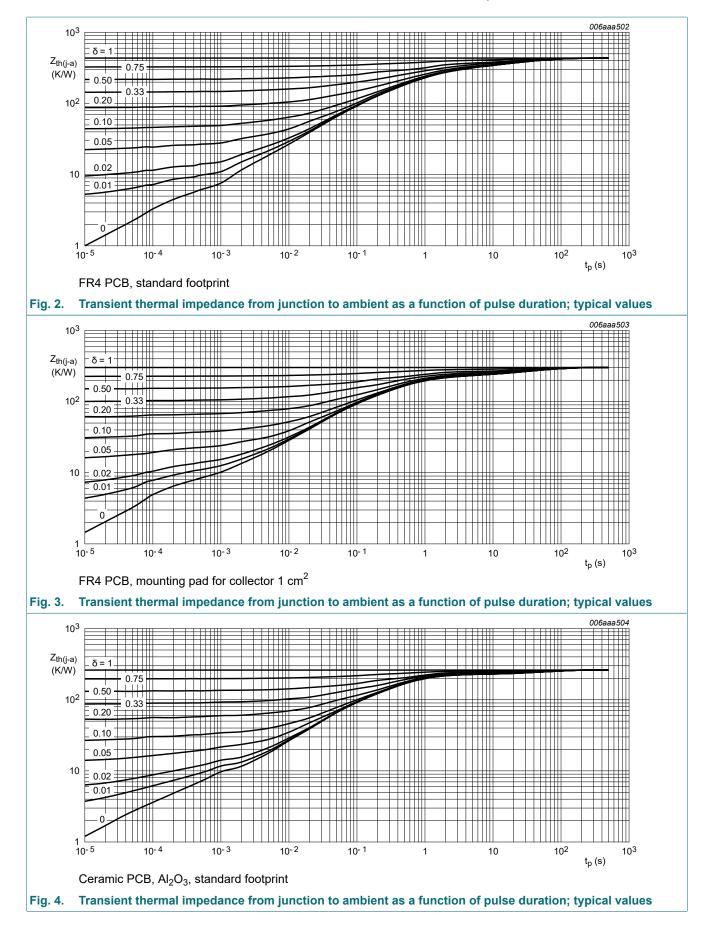
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
R <sub>th(j-a)</sub>	R <sub>th(j-a)</sub> thermal resistance from junction to ambient		[1]	-	-	500	K/W
			[2]	-	-	357	K/W
		[3]	-	-	301	K/W	
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	150	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

[3] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.

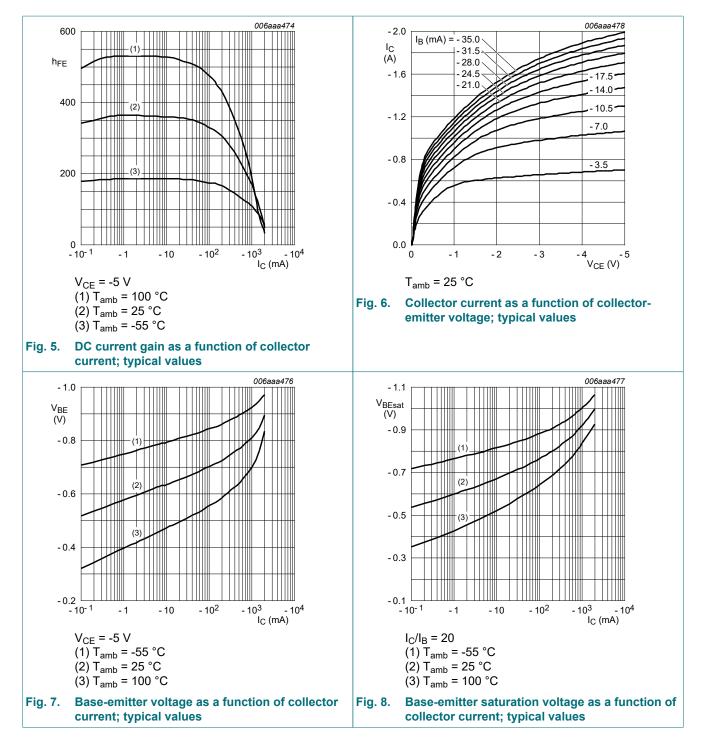
#### 60 V, 1 A PNP low VCEsat transistor



### **10. Characteristics**

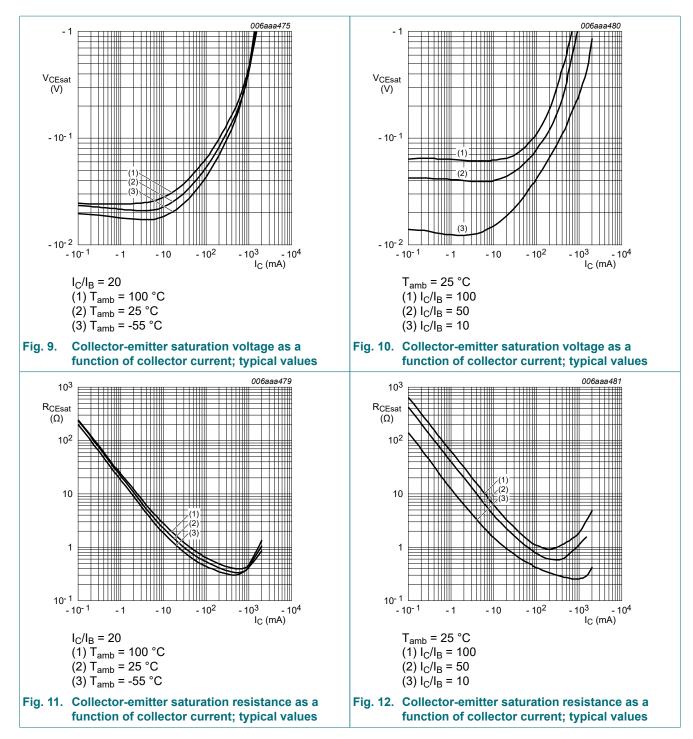
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = -60 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-100	nA
	current	V <sub>CB</sub> = -60 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	-50	μA
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = -5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-100	nA
I <sub>CES</sub>	collector-emitter cut-off current	$V_{CE}$ = -60 V; $V_{BE}$ = 0 V; $T_{amb}$ = 25 °C	-	-	-100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -1 mA; T <sub>amb</sub> = 25 °C	200	350	-	
		$V_{CE}$ = -5 V; I <sub>C</sub> = -500 mA; pulsed; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	150	250	-	
		V <sub>CE</sub> = -5 V; I <sub>C</sub> = -1 A; pulsed; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	100	160	-	
V <sub>CEsat</sub>	collector-emitter	I <sub>C</sub> = -100 mA; I <sub>B</sub> = -1 mA; T <sub>amb</sub> = 25 °C	-	-110	-175	mV
Sa	saturation voltage	$I_{C}$ = -500 mA; $I_{B}$ = -50 mA; $T_{amb}$ = 25 °C	-	-135	-180	mV
		$I_{C}$ = -1 A; $I_{B}$ = -100 mA; pulsed; $t_{p} \le$	-	-255	-340	mV
R <sub>CEsat</sub>	collector-emitter saturation resistance	300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	-	255	340	mΩ
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_{C}$ = -1 A; $I_{B}$ = -50 mA; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	-0.95	-1.1	V
V <sub>BEon</sub>	base-emitter turn-on voltage	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -1 A; pulsed; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	-	-0.82	-0.9	V
t <sub>d</sub>	delay time	I <sub>C</sub> = -0.5 A; I <sub>Bon</sub> = -25 mA; I <sub>Boff</sub> = 25 mA;	-	11	-	ns
t <sub>r</sub>	rise time	T <sub>amb</sub> = 25 °C	-	30	-	ns
t <sub>on</sub>	turn-on time		-	41	-	ns
t <sub>s</sub>	storage time		-	205	-	ns
t <sub>f</sub>	fall time		-	55	-	ns
t <sub>off</sub>	turn-off time		-	260	-	ns
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = -10 V; I <sub>C</sub> = -50 mA; f = 100 MHz; T <sub>amb</sub> = 25 °C	150	185	-	MHz
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = -10 V; I <sub>E</sub> = 0 A; i <sub>e</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C	-	9	15	pF

#### 60 V, 1 A PNP low VCEsat transistor



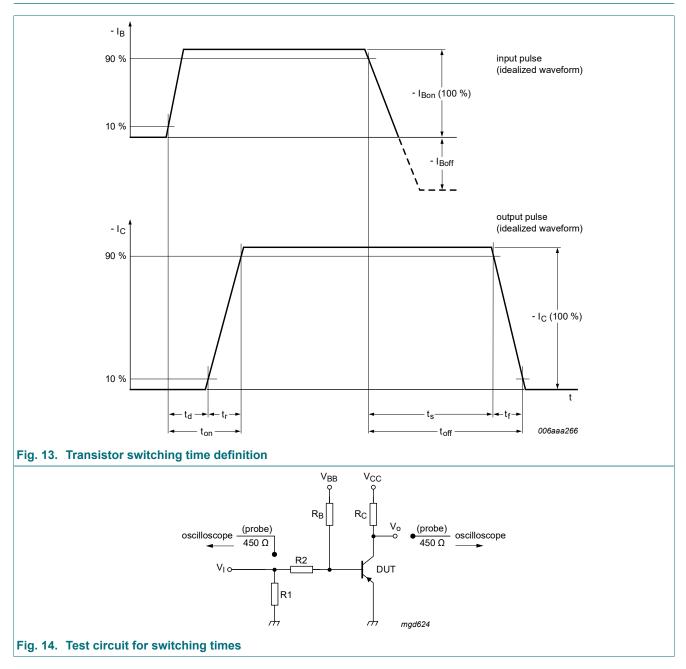
**Product data sheet** 

#### 60 V, 1 A PNP low VCEsat transistor



**Product data sheet** 

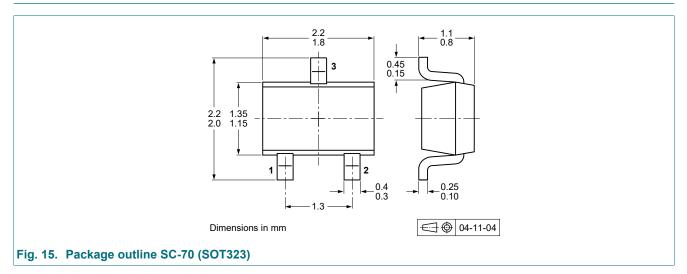
### **11. Test information**



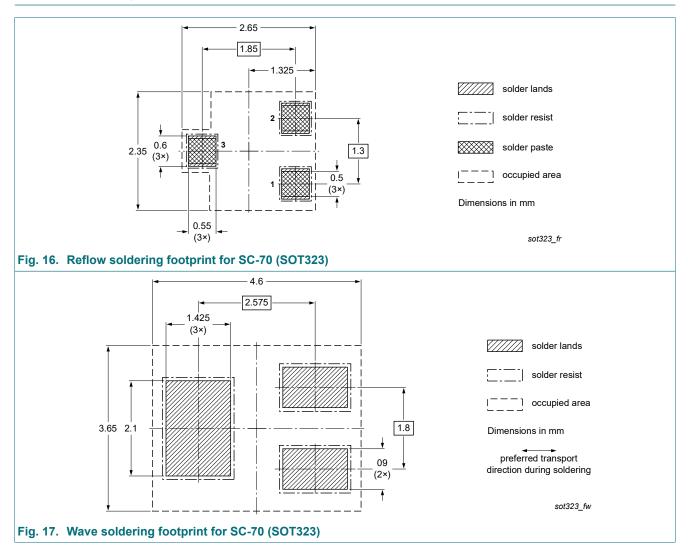
#### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### 12. Package outline



### 13. Soldering



### 14. Revision history

Table 8. Revision hi	story			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBSS5160U v.5	20231109	Product data sheet	-	PBSS5160U v.4
Modifications:	Nexperia. <ul> <li>Legal texts have</li> </ul>	his data sheet has been rede ve been adapted to the new c lation removed.		
PBSS5160U v.4	20081002	Product data sheet	-	PBSS5160U_3
PBSS5160U_3	20050811	Product data sheet	-	PBSS5160U_2
PBSS5160U_2	20040809	Objective data sheet	-	PBSS5160U_1
PBSS5160U_1	20040503	Objective data sheet	-	-

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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#### 60 V, 1 A PNP low VCEsat transistor

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### Contents

1. General description	1
2. Features and benefits	1
3. Applications	1
4. Quick reference data	1
5. Pinning information	2
6. Ordering information	2
7. Marking	2
8. Limiting values	2
9. Thermal characteristics	3
10. Characteristics	5
11. Test information	8
12. Package outline	9
13. Soldering	
14. Revision history	10
15. Legal information	

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